

LOW DROP DUAL POWER OPERATIONAL AMPLIFIER

- OUTPUT CURRENT TO 1 A
- OPERATES AT LOW VOLTAGES
- SINGLE OR SPLIT SUPPLY
- LARGE COMMON-MODE AND DIFFERENTIAL MODE RANGE
- LOW INPUT OFFSET VOLTAGE
- GROUND COMPATIBLE INPUTS
- LOW SATURATION VOLTAGE
- THERMAL SHUTDOWN
- CLAMP DIODE



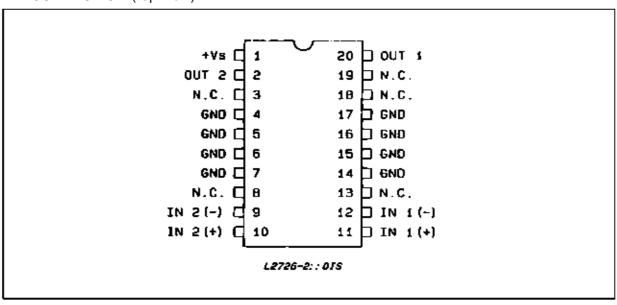
DESCRIPTION

The L2726 is a monolithic integrated circuit in SO-20 package intended for use as power operational amplifiers in a wide range of applications including servo amplifiers and power supplies.

It is particularly indicated for driving inductive loads, as motor and finds applications in compact-disc VCR automative, etc.

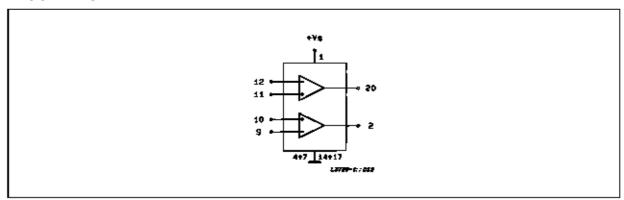
The high gain and high output power capability provide superior performance whatever an operational amplifier/power booster combination is required.

PIN CONNECTION (top view)

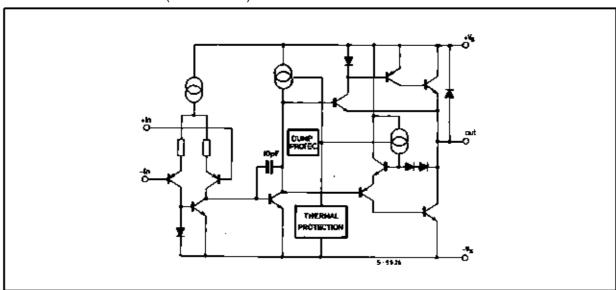


April 1993 1/6

BLOCK DIAGRAM



SCHEMATIC DIAGRAM (one section)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Vs	Supply Voltage	28	V
Vs	Peak Supply Voltage (50ms)	50	V
Vi	Input Voltage	V _s	
Vi	Differential Input Voltage	± V _s	
Io	DC Output Current	1	Α
Ip	Peak Output Current (non repetitive)	1.5	Α
P _{tot}	Power Dissipation at $T_{amb} = 85^{\circ}C$ $T_{case} = 75^{\circ}C$	1 5	W
T _{op}	Operating Temperature	- 40 to 85	°C
T _{stg} , T _j	Storage and Junction Temperature	- 40 to 150	°C

THERMAL DATA

R _{th j-case}	Thermal Resistance Junction-case	Max.	15.0	°C/W
R _{th j-amb}	Thermal Resistance Junction-ambient (*)	Max.	65	°C/W

^(*) With 4 sq. cm copper area heatsink.

ELECTRICAL CHARACTERISTICS

 $V_s = 24V$, $T_{amb} = 25^{\circ}C$ unless otherwise specified

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
Vs	Single Supply Voltage			4		28	V
Vs	Split Supply Voltage			± 2		± 14	V
Is	Quiescent Drain Current	$V_0 = \frac{V_s}{2}$	V _s = 24V		10	15	mA
<u> </u>	1 15: 0		V _s = 24V		9	15	
l _b	Input Bias Current				0.2	1	μΑ
V _{os}	Input Offset Voltage					10	mV
I _{os}	Input Offset Current					100	nA
SR	Slew Rate				2		V/μs
В	Gain-bandwidth Product				1.2		MHz
Ri	Input Resistance			500			kΩ
Gv	O. L. Voltage Gain	f = 100Hz f = 1kHz		70	80 60		dB
e _N	Input Noise Voltage	B = 22Hz to 22kHz			10		μV
I _N	Input Noise Voltage	D = 22M2 (0 22KM2			200		pА
CMR	Common Mode Rejection	f = 1kHz		66	84		dB
SVR	Supply Voltage Rejection	$ f = 100 Hz \\ R_G = 10 k\Omega \\ V_R = 0.5 V $	$V_s = 24V$ $V_s = \pm 12V$ $V_s = \pm 6V$	60	70 75 80		dB dB dB
V _{DROP(HIGH)}		$V_s = \pm 2.5V \text{ to } \pm 12V$	I _p = 100mA I _p = 500mA		0.7 1	1.5	V
V _{DROP(LOW)}		$V_s = \pm 2.5V \text{ to } \pm 12V$	I _p = 100mA I _p = 500mA		0.3 0.5	1	V
Cs	Channel Separation	$ f = 1 \text{KHz} \\ R_L = 10 \Omega \\ G_V = 30 \text{dB} $	V _s = 24V V _s = 6V		60 60		dB
T _{sd}	Thermal Shutdown Junction Temperature					145	°C

Figure 1: Quiescent Current vs. Supply Voltage

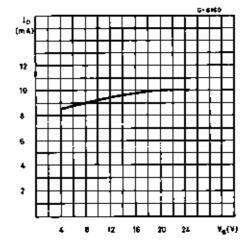


Figure 2 : Open Loop Gain vs. Frequency

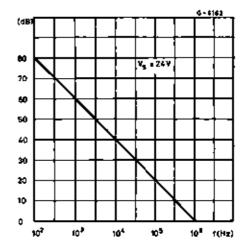


Figure 3: Common Mode Rejection Frequency

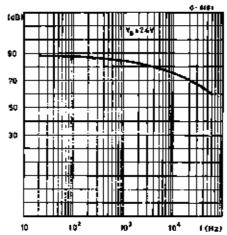


Figure 5 : Output Swing vs. Load Current $(V_s = \pm 12 \text{ V})$

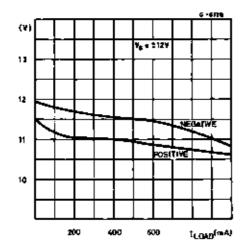


Figure 7: Channel Separation vs. Frequency.

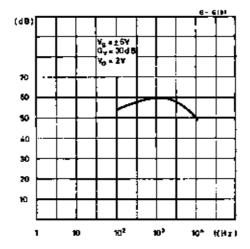


Figure 4 : Output Swing vs. Load Current $(V_s = \pm 5V)$

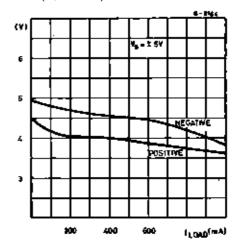
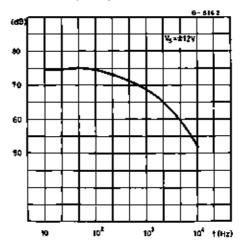
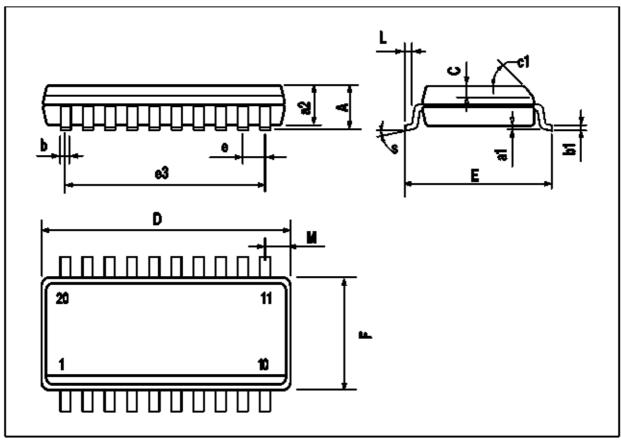


Figure 6 : Supply Voltage Rejection vs. Frequency



SO20 PACKAGE MECHANICAL DATA

DIM.	mm			inch			
Dilvi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А			2.65			0.104	
a1	0.1		0.2	0.004		0.008	
a2			2.45			0.096	
b	0.35		0.49	0.014		0.019	
b1	0.23		0.32	0.009		0.013	
С		0.5			0.020		
c1	45 (typ.)						
D	12.6		13.0	0.496		0.510	
E	10		10.65	0.394		0.419	
е		1.27			0.050		
e3		11.43			0.450		
F	7.4		7.6	0.291		0.300	
L	0.5		1.27	0.020		0.050	
М			0.75			0.030	
S	8 (max.)						



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